

74LVC2G04

Dual Inverter

GENERAL DESCRIPTION

The 74LVC2G04 contains two independent inverters and it is designed for 1.65V to 5.5V V_{CC} operation. The device performs the Boolean function $Y = \bar{A}$.

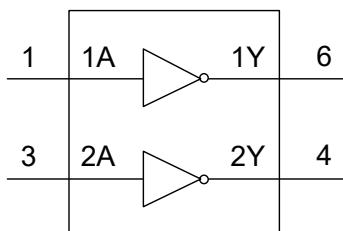
Inputs can be driven from either 3.3V or 5V devices. This feature allows the use of this device as a translator in a mixed 3.3V and 5V environment.

This device is fully specified for partial power-down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

FEATURES

- 5V Tolerant Inputs for Interfacing with 5V Logic
- Wide Supply Voltage Range: 1.65V to 5.5V
- High Noise Immunity
- $\pm 24\text{mA}$ Output Drive at $V_{CC} = 3.0\text{V}$
- CMOS Low Power Consumption
- Direct Interface with TTL Levels
- Inputs Accept Voltages up to 5V
- -40°C to +125°C Operating Temperature Range
- Available in a Green SOT-23-6 Package

LOGIC SYMBOL



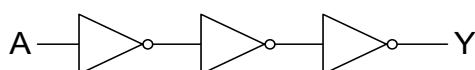
FUNCTION TABLE

| INPUT | OUTPUT |
|-------|--------|
| nA | nY |
| L | H |
| H | L |

H = High Voltage Level

L = Low Voltage Level

LOGIC DIAGRAM

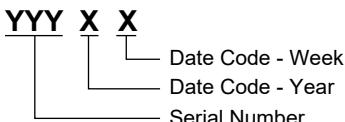


PACKAGE/ORDERING INFORMATION

| MODEL | PACKAGE DESCRIPTION | SPECIFIED TEMPERATURE RANGE | ORDERING NUMBER | PACKAGE MARKING | PACKING OPTION |
|-----------|---------------------|-----------------------------|------------------|-----------------|---------------------|
| 74LVC2G04 | SOT-23-6 | -40°C to +125°C | 74LVC2G04XN6G/TR | R53XX | Tape and Reel, 3000 |

MARKING INFORMATION

NOTE: XX = Date Code.



Green (RoHS & HSF): SG Micro Corp defines "Green" to mean Pb-Free (RoHS compatible) and free of halogen substances. If you have additional comments or questions, please contact your SGMICRO representative directly.

ABSOLUTE MAXIMUM RATINGS ⁽¹⁾

| | |
|---|---------------------------------|
| Supply Voltage, V _{CC} | -0.5V to 6.5V |
| Input Voltage, V _I ⁽²⁾ | -0.5V to 6.5V |
| Output Voltage, V _O ⁽²⁾ ⁽³⁾ | |
| Active Mode | -0.5V to V _{CC} + 0.5V |
| Power-Down Mode | -0.5V to 6.5V |
| Input Clamping Current, I _{IK} (V _I < 0V)..... | -50mA |
| Output Clamping Current, I _{OK} (V _O > V _{CC} or V _O < 0V)..... | ±50mA |
| Output Current, I _O (V _O = 0V to V _{CC}) | ±50mA |
| Supply Current, I _{CC} | 100mA |
| Ground Current, I _{GND} | -100mA |
| Junction Temperature ⁽⁴⁾ | +150°C |
| Storage Temperature Range | -65°C to +150°C |
| Lead Temperature (Soldering, 10s) | +260°C |
| ESD Susceptibility | |
| HBM..... | 8000V |
| CDM | 1000V |

RECOMMENDED OPERATING CONDITIONS

| | |
|---|-----------------------|
| Supply Voltage, V _{CC} | 1.65V to 5.5V |
| Input Voltage, V _I | 0V to 5.5V |
| Output Voltage, V _O | |
| Active Mode | 0V to V _{CC} |
| Power-Down Mode, V _{CC} = 0V | 0V to 5.5V |
| Input Transition Rise and Fall Rate, Δt/ΔV | |
| V _{CC} = 1.65V to 2.7V..... | 20ns/V (MAX) |
| V _{CC} = 2.7V to 5.5V | 10ns/V (MAX) |
| Operating Temperature Range | -40°C to +125°C |

OVERSTRESS CAUTION

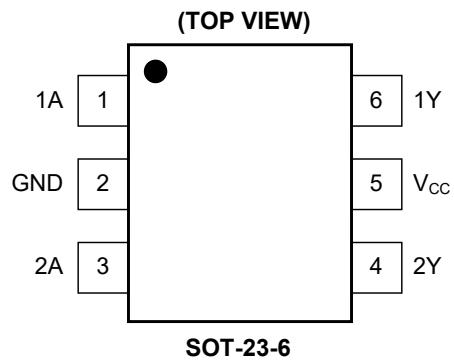
- Stresses beyond those listed in Absolute Maximum Ratings may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect reliability. Functional operation of the device at any conditions beyond those indicated in the Recommended Operating Conditions section is not implied.
- The input and output voltage ratings may be exceeded if the input and output clamp current ratings are observed.
- When V_{CC} = 0V (power-down mode), the output voltage can be 5.5V in normal operation.
- The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability.

ESD SENSITIVITY CAUTION

This integrated circuit can be damaged if ESD protections are not considered carefully. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because even small parametric changes could cause the device not to meet the published specifications.

DISCLAIMER

SG Micro Corp reserves the right to make any change in circuit design, or specifications without prior notice.

PIN CONFIGURATION**PIN DESCRIPTION**

| PIN | NAME | FUNCTION |
|------|--------|-----------------|
| 1, 3 | 1A, 2A | Data Inputs. |
| 2 | GND | Ground. |
| 4, 6 | 2Y, 1Y | Data Outputs. |
| 5 | Vcc | Supply Voltage. |

ELECTRICAL CHARACTERISTICS(Full = -40°C to +125°C, all typical values are measured at $V_{CC} = 3.3V$ and $T_A = +25^\circ C$, unless otherwise noted.)

| PARAMETER | SYMBOL | CONDITIONS | TEMP | MIN | TYP | MAX | UNITS |
|---------------------------|-----------------|--|--|----------------------|-----------------|----------------------|---------|
| High-Level Input Voltage | V_{IH} | $V_{CC} = 1.65V \text{ to } 1.95V$ | Full | $0.65 \times V_{CC}$ | | | V |
| | | $V_{CC} = 2.3V \text{ to } 2.7V$ | Full | 1.7 | | | |
| | | $V_{CC} = 2.7V \text{ to } 3.6V$ | Full | 2 | | | |
| | | $V_{CC} = 4.5V \text{ to } 5.5V$ | Full | $0.7 \times V_{CC}$ | | | |
| Low-Level Input Voltage | V_{IL} | $V_{CC} = 1.65V \text{ to } 1.95V$ | Full | | | $0.35 \times V_{CC}$ | V |
| | | $V_{CC} = 2.3V \text{ to } 2.7V$ | Full | | | 0.7 | |
| | | $V_{CC} = 2.7V \text{ to } 3.6V$ | Full | | | 0.8 | |
| | | $V_{CC} = 4.5V \text{ to } 5.5V$ | Full | | | $0.3 \times V_{CC}$ | |
| High-Level Output Voltage | V_{OH} | $V_I = V_{IH}$ or V_{IL} | $V_{CC} = 1.65V \text{ to } 5.5V, I_O = -100\mu A$ | Full | $V_{CC} - 0.05$ | $V_{CC} - 0.01$ | V |
| | | | $V_{CC} = 1.65V, I_O = -4mA$ | Full | 1.43 | 1.55 | |
| | | | $V_{CC} = 2.3V, I_O = -8mA$ | Full | 2.02 | 2.18 | |
| | | | $V_{CC} = 2.7V, I_O = -12mA$ | Full | 2.38 | 2.56 | |
| | | | $V_{CC} = 3.0V, I_O = -24mA$ | Full | 2.52 | 2.74 | |
| | | | $V_{CC} = 4.5V, I_O = -32mA$ | Full | 4 | 4.22 | |
| Low-Level Output Voltage | V_{OL} | $V_I = V_{IH}$ or V_{IL} | $V_{CC} = 1.65V \text{ to } 5.5V, I_O = 100\mu A$ | Full | | 0.01 | 0.05 |
| | | | $V_{CC} = 1.65V, I_O = 4mA$ | Full | | 0.1 | 0.22 |
| | | | $V_{CC} = 2.3V, I_O = 8mA$ | Full | | 0.12 | 0.28 |
| | | | $V_{CC} = 2.7V, I_O = 12mA$ | Full | | 0.16 | 0.34 |
| | | | $V_{CC} = 3.0V, I_O = 24mA$ | Full | | 0.3 | 0.56 |
| | | | $V_{CC} = 4.5V, I_O = 32mA$ | Full | | 0.32 | 0.6 |
| Input Leakage Current | I_I | $V_{CC} = 0V \text{ to } 5.5V, V_I = 5.5V \text{ or GND}$ | Full | | ± 0.01 | ± 1 | μA |
| Power-Off Leakage Current | I_{OFF} | $V_{CC} = 0V, V_I \text{ or } V_O = 5.5V$ | Full | | ± 0.01 | ± 1 | μA |
| Supply Current | I_{CC} | $V_{CC} = 1.65V \text{ to } 5.5V, V_I = 5.5V \text{ or GND}, I_O = 0A$ | Full | | 0.01 | 1 | μA |
| Additional Supply Current | ΔI_{CC} | Per pin, $V_{CC} = 2.3V \text{ to } 5.5V, V_I = V_{CC} - 0.6V, I_O = 0A$ | Full | | 0.05 | 10 | μA |
| Input Capacitance | C_I | $V_{CC} = 3.3V, V_I = \text{GND to } V_{CC}$ | +25°C | | 3.5 | | pF |

DYNAMIC CHARACTERISTICS

(For test circuit, see Figure 1. Full = -40°C to +125°C, all typical values are measured at $T_A = +25^\circ\text{C}$ and $V_{CC} = 1.8\text{V}, 2.5\text{V}, 2.7\text{V}, 3.3\text{V}$ and 5.0V respectively, unless otherwise noted.)

| PARAMETER | SYMBOL | CONDITIONS | | TEMP | MIN ⁽¹⁾ | TYP | MAX ⁽¹⁾ | UNITS |
|--|----------|---|---|-------|--------------------|------|--------------------|-------|
| Propagation Delay ⁽²⁾ | t_{PD} | nA to nY, see Figure 2 | $V_{CC} = 1.65\text{V}$ to 1.95V | Full | 0.5 | 6.0 | 14.0 | ns |
| | | | $V_{CC} = 2.3\text{V}$ to 2.7V | Full | 0.5 | 3.2 | 7.0 | |
| | | | $V_{CC} = 2.7\text{V}$ | Full | 0.5 | 3.1 | 7.5 | |
| | | | $V_{CC} = 3.0\text{V}$ to 3.6V | Full | 0.1 | 3.5 | 6.0 | |
| | | | $V_{CC} = 4.5\text{V}$ to 5.5V | Full | 0.1 | 3.1 | 5.5 | |
| Power Dissipation Capacitance ⁽³⁾ | C_{PD} | $V_{CC} = 3.3\text{V}$, $V_I = \text{GND}$ to V_{CC} | | +25°C | | 30.5 | | pF |

NOTES:

1. Specified by design and characterization; not production tested.
2. t_{PD} is the same as t_{PLH} and t_{PHL} .
3. C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum(C_L \times V_{CC}^2 \times f_o)$$

where:

f_i = Input frequency in MHz.

f_o = Output frequency in MHz.

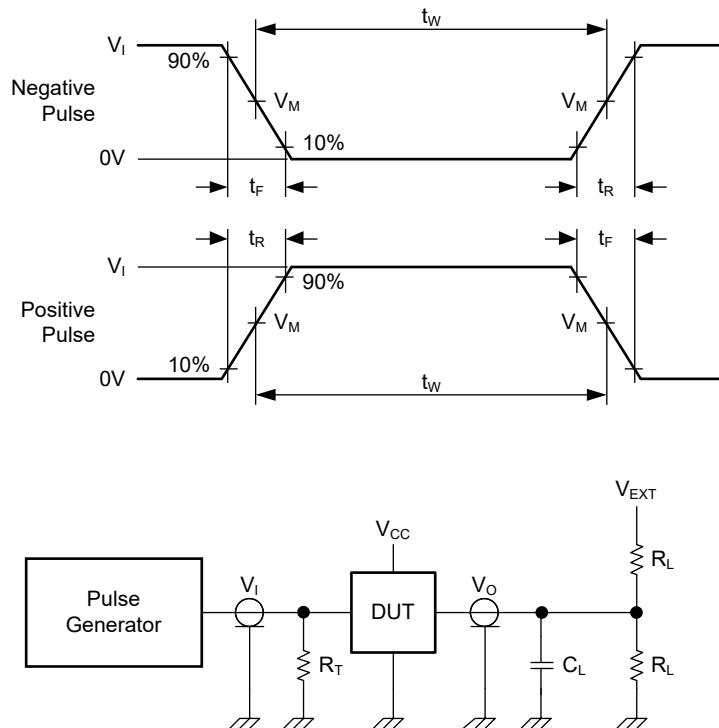
C_L = Output load capacitance in pF.

V_{CC} = Supply voltage in Volts.

N = Number of inputs switching.

$\sum(C_L \times V_{CC}^2 \times f_o)$ = Sum of outputs.

TEST CIRCUIT



Test conditions are given in Table 1.

Definitions for test circuit:

R_L = Load resistance.

C_L = Load capacitance including jig and probe capacitance.

R_T = Termination resistance should be equal to the output impedance Z_O of the pulse generator.

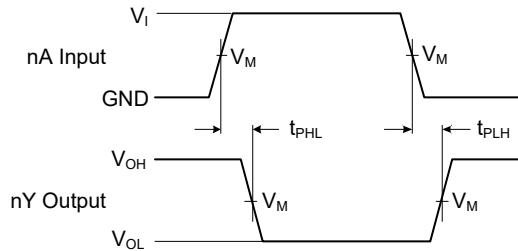
V_{EXT} = External voltage for measuring switching times.

Figure 1. Test Circuit for Measuring Switching Times

Table 1. Test Conditions

| SUPPLY VOLTAGE | INPUT | | LOAD | | V_{EXT} |
|----------------|----------|---------------------|-------|--------------|--------------------|
| V_{cc} | V_I | $t_R = t_F$ | C_L | R_L | t_{PLH}, t_{PHL} |
| 1.65V to 1.95V | V_{cc} | $\leq 2.0\text{ns}$ | 30pF | 1k Ω | Open |
| 2.3V to 2.7V | V_{cc} | $\leq 2.0\text{ns}$ | 30pF | 500 Ω | Open |
| 2.7V | 2.7V | $\leq 2.5\text{ns}$ | 50pF | 500 Ω | Open |
| 3.0V to 3.6V | 2.7V | $\leq 2.5\text{ns}$ | 50pF | 500 Ω | Open |
| 4.5V to 5.5V | V_{cc} | $\leq 2.5\text{ns}$ | 50pF | 500 Ω | Open |

WAVEFORMS



Test conditions are given in Table 1.

Measurement points are given in Table 2.

Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Figure 2. Input nA to Output nY Propagation Delays

Table 2. Measurement Points

| SUPPLY VOLTAGE | INPUT | OUTPUT |
|----------------|--------------------|--------------------|
| V_{CC} | $V_M^{(1)}$ | V_M |
| 1.65V to 1.95V | 0.5V _{CC} | 0.5V _{CC} |
| 2.3V to 2.7V | 0.5V _{CC} | 0.5V _{CC} |
| 2.7V | 1.5V | 1.5V |
| 3.0V to 3.6V | 1.5V | 1.5V |
| 4.5V to 5.5V | 0.5V _{CC} | 0.5V _{CC} |

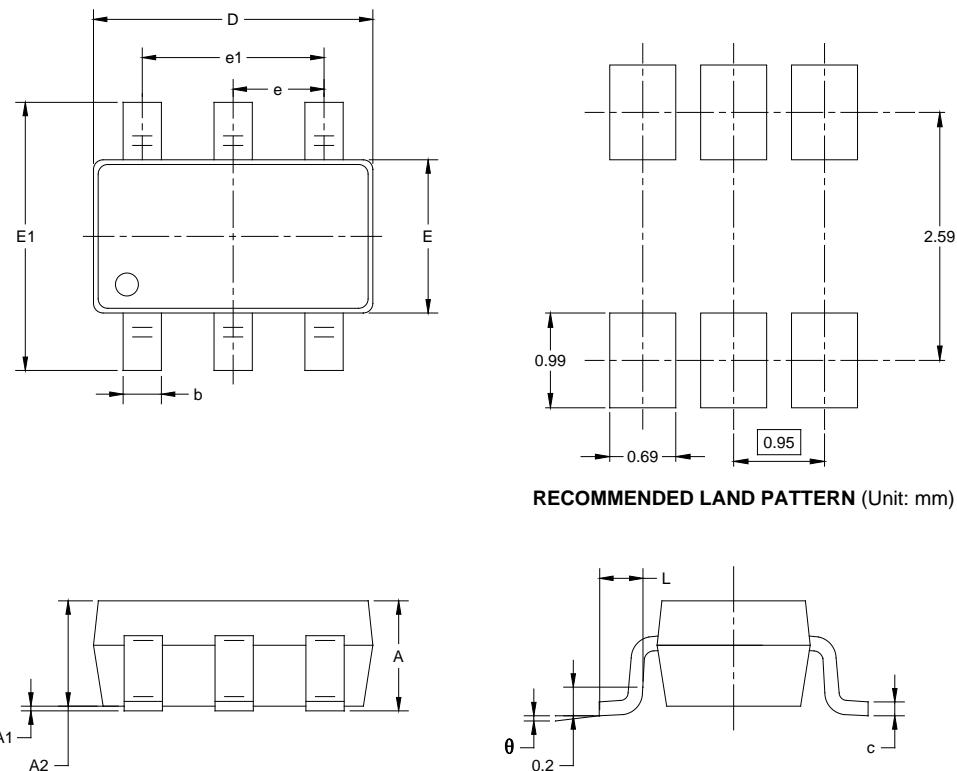
NOTE:

1. The measurement points should be V_{IH} or V_{IL} when the input rising or falling time exceeds 2.5ns.

PACKAGE INFORMATION

PACKAGE OUTLINE DIMENSIONS

SOT-23-6

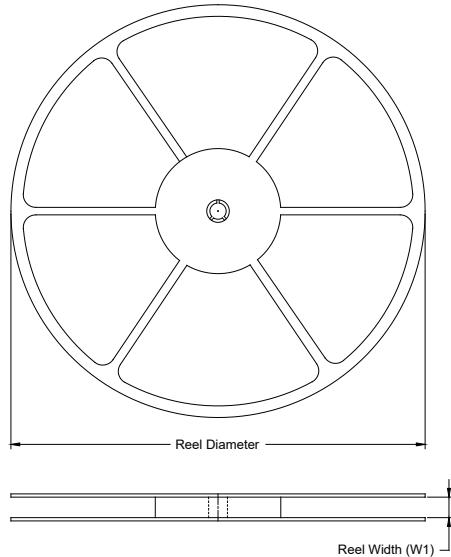


| Symbol | Dimensions In Millimeters | | Dimensions In Inches | |
|--------|------------------------------|-------|-------------------------|-------|
| | MIN | MAX | MIN | MAX |
| A | 1.050 | 1.250 | 0.041 | 0.049 |
| A1 | 0.000 | 0.100 | 0.000 | 0.004 |
| A2 | 1.050 | 1.150 | 0.041 | 0.045 |
| b | 0.300 | 0.500 | 0.012 | 0.020 |
| c | 0.100 | 0.200 | 0.004 | 0.008 |
| D | 2.820 | 3.020 | 0.111 | 0.119 |
| E | 1.500 | 1.700 | 0.059 | 0.067 |
| E1 | 2.650 | 2.950 | 0.104 | 0.116 |
| e | 0.950 BSC | | 0.037 BSC | |
| e1 | 1.900 BSC | | 0.075 BSC | |
| L | 0.300 | 0.600 | 0.012 | 0.024 |
| θ | 0° | 8° | 0° | 8° |

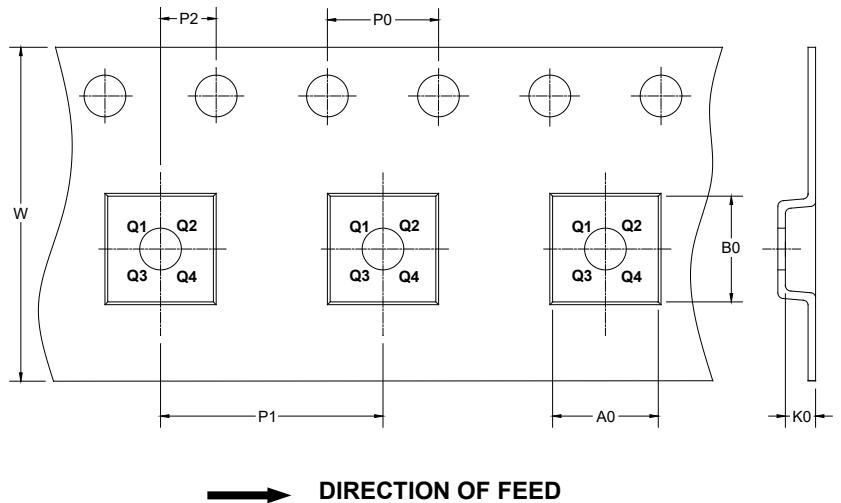
PACKAGE INFORMATION

TAPE AND REEL INFORMATION

REEL DIMENSIONS



TAPE DIMENSIONS



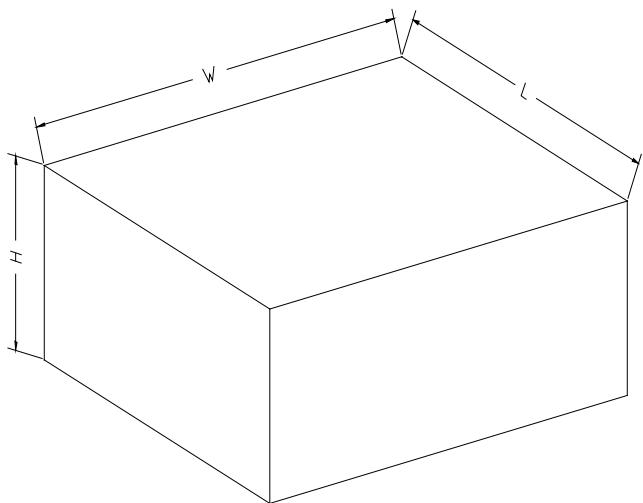
NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF TAPE AND REEL

| Package Type | Reel Diameter | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P0 (mm) | P1 (mm) | P2 (mm) | W (mm) | Pin1 Quadrant |
|--------------|---------------|--------------------|---------|---------|---------|---------|---------|---------|--------|---------------|
| SOT-23-6 | 7" | 9.5 | 3.17 | 3.23 | 1.37 | 4.0 | 4.0 | 2.0 | 8.0 | Q3 |

PACKAGE INFORMATION

CARTON BOX DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF CARTON BOX

| Reel Type | Length (mm) | Width (mm) | Height (mm) | Pizza/Carton |
|-------------|-------------|------------|-------------|--------------|
| 7" (Option) | 368 | 227 | 224 | 8 |
| 7" | 442 | 410 | 224 | 18 |

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